

# Plasma Processes as a Cleaner Alternative for Cleaning, Corrosion Resistance, and Functionalization of Metallic Surfaces

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*Those who are inspired by a model other than Nature, a mistress above all masters, are laboring in vain. - Leonardo Da Vinci*

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ÁREA DE CONCENTRAÇÃO DE PESQUISA

CÊNCIA E TECNOLOGIA DE MATERIAIS

# OBJECTIVES

- ✓ Development of clean and efficient high vacuum technologies
- ✓ Replacement for traditional methods for metallic or polymeric surfaces
- ✓ Treatments to clean , deposit thin films , and functionalize surfaces
- ✓ One - dimensional nanotechnology
- ✓ Development of environmentally friendly and sustainable technologies

# TREATMENT SEQUENCE

- Removal of oil from aluminium surfaces
- Deposition of a thin film of HMDSO
- Functionalization of the HMDSO film

# PLASMA EQUIPMENT \*

Fabricated by Diener Electronic - Plasma Surface Technology, Germany, Series Pico with a cylindrical chamber with capacity of 5 liters.

The generator works with radio-frequency signal of 40 khz and maximum power of 200w.

Pump Ilmvac mark, with 1.8 m<sup>3</sup>/h and pressure of  $3 \times 10^{-2}$  mbar

\* Made available by SABO

# VARIABLES STUDIED

- Gas composition
- Reactor Power
- Pressure
- Exposure Time

# CLEANING PROCESS

- Radio-frequency signal of 40 kHz , maximum power of 200W
- Pressure of 0,075 Torr
- Oxygen (99% of purity) immediately introduced.
- Contact angle –Before treatment , 90 ; After, 12.6

# DEPOSITION PROCESS

- Monomer : HMDSO , co-reagent : Argon
- HMDSO pressure: 0.03 mbar ; Ar pressure: 0.18 mbar
- Power: 30, 45, 60W; time : 5-30min.
- Most effective conditions - pressure: HMDSO 0,03 Torr; Ar pressure: 0,15 Torr; Power: 30W; time: 15 minutes
- Thickness of the layer obtained: 943 *nm*; deposition rate: 62.9 *nm/min*

*Note: Film Functionalization in Progress*



# XPS RESULTS-CLEANING

- ✓ Reduction of the concentration of atomic C 1s from 86.14 to 44.47% due to the removal of the protective oil from the surface of aluminum,
- ✓ Increase in the atomic concentration of O 1s from 12,55 to 27.97%
- ✓ Increase in the concentration of atomic Al 2p from 1.34 % to 27.55%.

# CONTACT ANGLE MEASUREMENTS

		Contact Angle		Surface Free Energy (mN/m)		
		Pure water	Ethylene glycol	$\gamma_L^d$ (mN/m)	$\gamma_L^p$ (mN/m)	$\gamma_L$ (mN/m)
Before treatment	plasma	95.5	77.0	12.06	5.82	17.88
After treatment	Plasma	7.6	16.8	2.46	79.30	81.76

# SALT SPRAY TESTS

## EVALUATION OF CORROSION RESISTANCE ALUMINUM SAMPLES PROTECTED BY THE HDMSO FILMS

ASTM B 117 , ASTM D 1654 , E ABNT NBR 8094

TEST CONDITIONS USED WERE:  $5\% \pm 1\%$  AQUEOUS SOLUTION OF SODIUM CHLORIDE (THE PH OF THE SOLUTION WAS ADJUSTED FROM 6.5 TO 7.2). THE AIR TEMPERATURE WAS MAINTAINED AT  $35 \pm 2^{\circ}\text{C}$

## RESULTS

CONSIDERABLE IMPROVEMENT: PROTECTED PLATES CORRODED ONLY WHERE PROTECTIVE FILM DID NOT COAT UNIFORMLY- EVEN AFTER 3 WEEKS EXPOSURE

# CONCLUSÕES

- Significant surface modification was obtained with plasma exposure time of 30 seconds.
- Using argon plasma, after the activation step the contact angle obtained was  $12.6^\circ$ , associated to an increase in surface energy of  $95.48 \text{ mJ/m}^2$ ;
- The argon plasma doesn't introduce new chemical groups in the surfaces. But is effective in surface cleaning, and surface crosslinking. However we observe the introduction of  $-\text{OH}$  groups, when the sample is exposed to air, after the argon plasma treatment.
- The plasma process is clean, with very low production of residues, consisting in an ecologically friendly technique.
- Using plasma technology is possible to develop an industrial process to clean, deposit and activate surfaces with very low ecological damage compared to wet processes

**MUITO OBRIGADO**